TOSHIBA GTR Module Silicon N Channel IGBT

MG300J2YS50

High Power Switching Applications Motor Control Applications

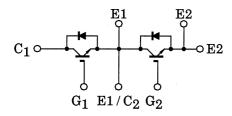
- The electrodes are isolated from case.
- High input impedance
- Includes a complete half bridge in one package.
- Enhancement-mode
- High speed : $t_f = 0.30 \mu s$ (max) (IC = 300A)

 $t_{rr} = 0.15 \mu s \text{ (max) (IF} = 300 \text{A)}$

• Low saturation voltage

: VCE (sat) = 2.70V (max) (IC = 300A)

Equivalent Circuit



Unit: mm $4 - 6.6 \pm 0.3$ 4-FAST-ON-TAB #110 35 ± 0.8 48 ± 0.3 62 ± 0.8 28 ± 0.6 28 ± 0.6 80 ± 0.8 93 ± 0.3 108 ± 0.8 3 ± 0.3 $\begin{vmatrix} 49 \pm 0.6 \\ 3 \pm 0.3 \end{vmatrix}$ 20.5 ± 0.6 | 25 ± 0.6 | 20.5 ± 0.6 23 +2.6 106 ± 0.8 60 ± 0.8 JEDEC JEITA 2-109C1A **TOSHIBA**

Weight: 430g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	IC	300	А	
	1ms	I _{CP}	600		
Forward current	DC	IF	300	А	
	1ms	I _{FM}	600		
Collector power dissipation (Tc = 25°C)		P _C	1300	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)		_	3/3	N·m	

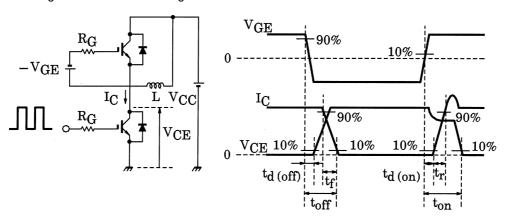
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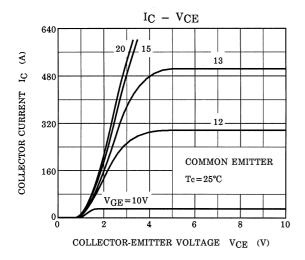
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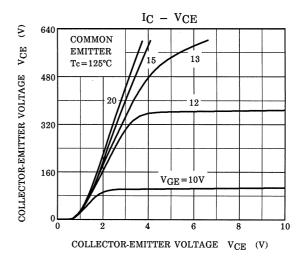
Electrical Characteristics (Ta = 25°C)

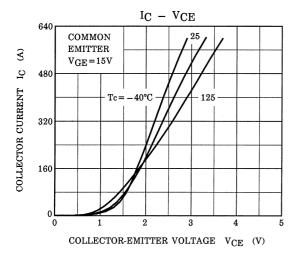
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 600V, V _{GE} = 0	_	_	2.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 30mA, V _{CE} = 5V	5.0	7.0	8.0	V
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 300A, V _{GE} = 15V	_	2.10	2.70	٧
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	30800	_	pF
Switching time	Turn-on delay time	t _{d (on)}	Inductive load $V_{CC}=300V$ $I_{C}=300A$ $V_{GE}=\pm15V$ $R_{G}=1.8\Omega$ (Note 1)	_	0.20	0.40	μs
	Rise time	t _r		_	0.15	0.30	
	Turn-on time	t _{on}		_	0.60	1.20	
	Turn-off delay time	t _{d (off)}		_	0.20	0.40	
	Fall time	t _f		_	0.15	0.30	
	Turn-off time	t _{off}		_	0.50	1.00	
Forward voltage		V _F	I _F = 300 A, V _{GE} = 0	_	2.30	3.00	V
Reverse recovery time		t _{rr}	$I_F = 300 \text{ A}, V_{GE} = -10 \text{ V},$ di / dt = 400 A / μ s	_	0.08	0.15	μs
Thermal resistance		R _{th (j-c)}	Transistor stage	_	_	0.096	°C/W
			Diode stage	_	_	0.20	

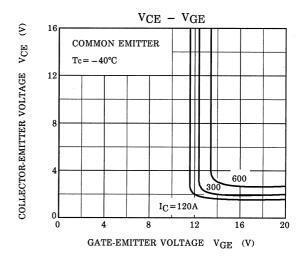
Note 1: Switching time test circuit & timing chart

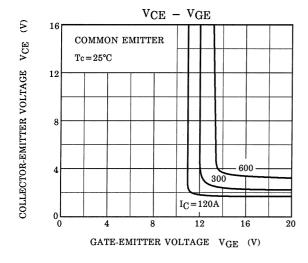


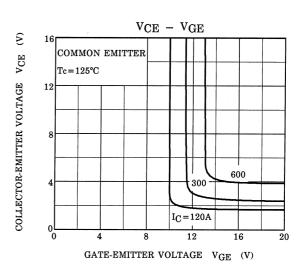


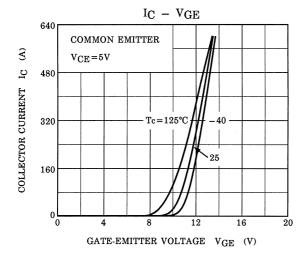


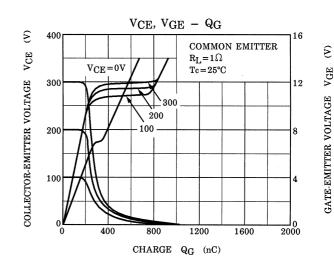


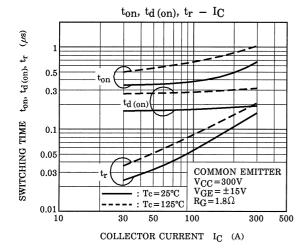


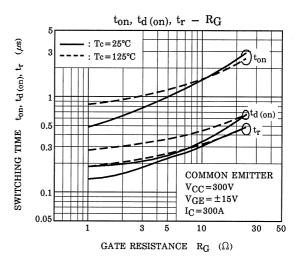


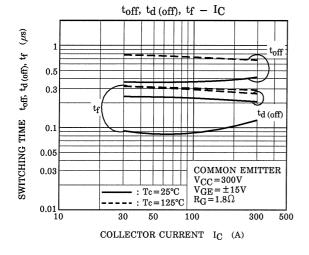


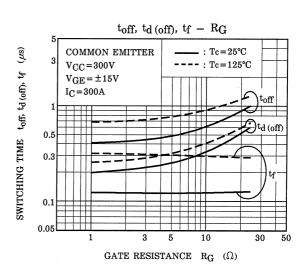




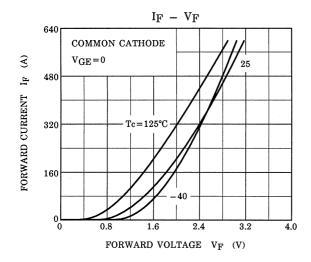


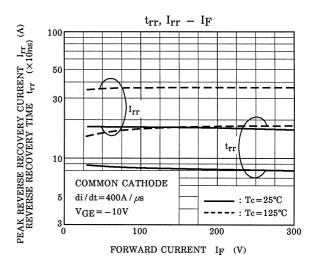


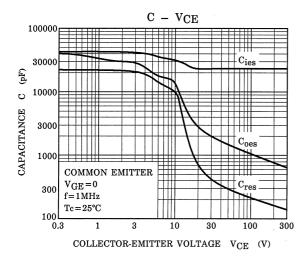


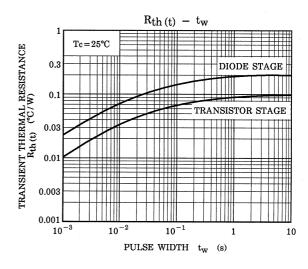


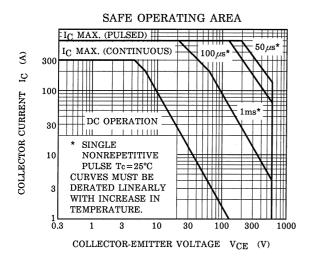
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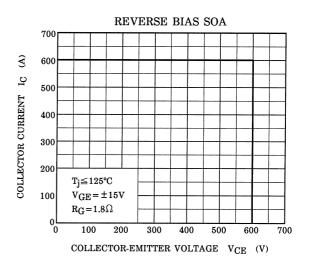












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